

5420/DM5420/DM7420 Dual 4-Input NAND Gates

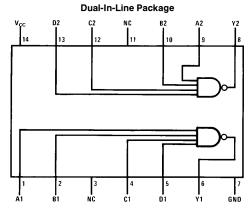
General Description

This device contains two independent gates each of which performs the logic NAND function.

Features

Alternate Military/Aerospace device (5420) is available. Contact a National Semiconductor Sales Office/Distributor for specifications.

Connection Diagram



TL/F/6506-

Order Number 5420DMQB, 5420FMQB, DM5420J, DM5420W or DM7420N See NS Package Number J14A, N14A or W14B

Function Table

 $\mathbf{Y} = \overline{\mathbf{ABCD}}$

	Inp	Output		
Α	В	С	D	Υ
Х	Х	Х	L	Н
X X X	Х	L	Х	Н
Х	L	Х	Х	Н
L	Х	Х	Х	Н
Н	Н	Н	Н	L

 $H = High \ Logic \ Level$

 $\mathsf{L} = \mathsf{Low} \; \mathsf{Logic} \; \mathsf{Level}$

 $X \,=\, \text{Either Low or High Logic Level}$

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 7V
Input Voltage 5.5V
Operating Free Air Temperature Range

Storage Temperature Range -65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	DM5402			DM7402			Units
		Min	Nom	Max	Min	Nom	Max	Onits
V _{CC}	Supply Voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH}	High Level Input Voltage	2			2			V
V _{IL}	Low Level Input Voltage			0.8			0.8	V
I _{OH}	High Level Output Current			-0.4			-0.4	mA
l _{OL}	Low Level Output Current			16			16	mA
T _A	Free Air Operating Temperature	-55		125	0		70	°C

Electrical Characteristics over recommended operating free air temperature range (unless otherwise noted)

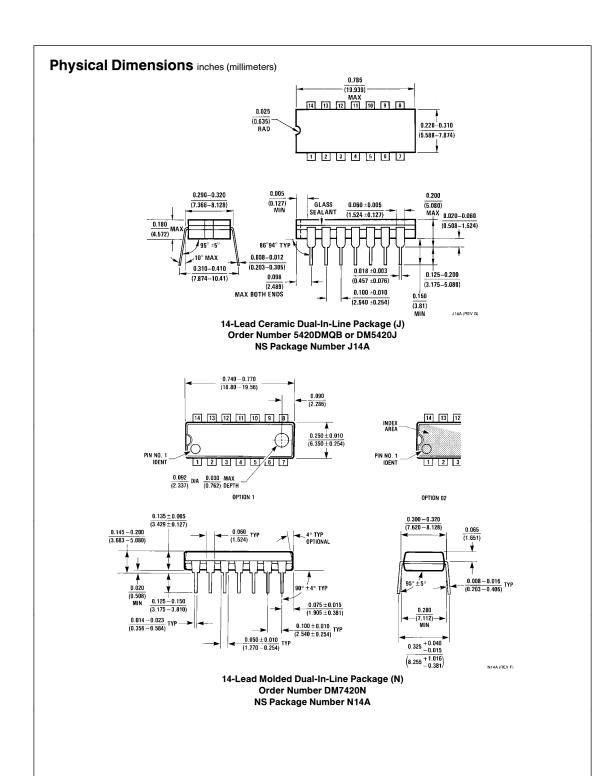
Symbol	Parameter	Conditions		Min	Typ (Note 1)	Max	Units
VI	Input Clamp Voltage	V _{CC} = Min, I _I =	= -12 mA			-1.5	V
V _{OH}	High Level Output Voltage	$V_{CC} = Min, I_{OH} = Max$ $V_{IL} = Max$		2.4	3.4		V
V _{OL}	Low Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min$			0.2	0.4	V
I _I	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$				1	mA
I _{IH}	High Level Input Current	$V_{CC} = Max, V_I = 2.4V$				40	μΑ
I _{IL}	Low Level Input Current	$V_{CC} = Max, V_I = 0.4V$				-1.6	mA
los	Short Circuit Output Current	V _{CC} = Max (Note 2)	DM54	-20		-55	- mA
			DM74	-18		-55	
Іссн	Supply Current with Outputs High	V _{CC} = Max			2	4	mA
I _{CCL}	Supply Current with Outputs Low	V _{CC} = Max			6	11	mA

$\textbf{Switching Characteristics} \text{ at } V_{CC} = 5V \text{ and } T_A = 25^{\circ}C \text{ (See Section 1 for Test Waveforms and Output Load)}$

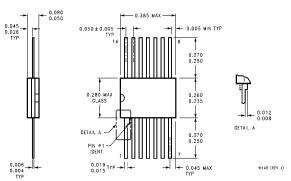
Symbol	Parameter	Conditions	Min	Max	Units
t _{PLH}	Propagation Delay Time Low to High Level Output	$C_L = 15 pF$ $R_L = 400 \Omega$		22	ns
t _{PHL}	Propagation Delay Time High to Low Level Output			15	ns

Note 1: All typicals are at $V_{CC}\,=\,5V,\,T_A\,=\,25^{\circ}C.$

Note 2: Not more than one output should be shorted at a time.



Physical Dimensions inches (millimeters) (Continued)



14-Lead Ceramic Flat Package (W)
Order Number 5420FMQB or DM5420W
NS Package Number W14B

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